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3. Ordering information

Table 2. Ordering information								
Type number	Package							
	Name	Description	Version					
BTA316-600B	SC-46	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead	SOT78					
BTA316-600C		TO-220AB						
BTA316-800B								
BTA316-800C								

4. Limiting values

Table 3.Limiting values

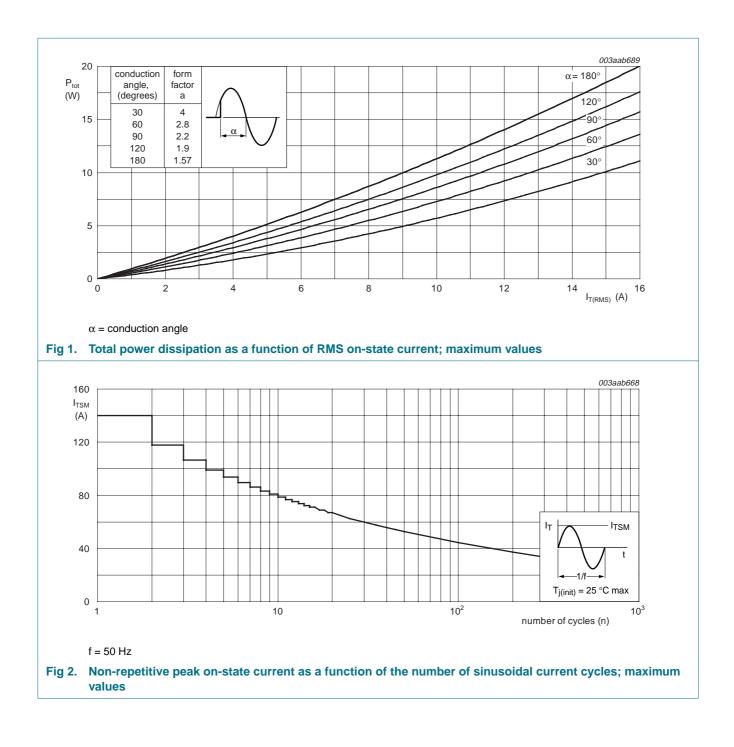
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage	BTA316-600B; BTA316-600C	<u>[1]</u> _	600	V
		BTA316-800B; BTA316-800C	-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 101 °C; see <u>Figure 4</u> and <u>5</u>	-	16	А
I _{TSM}	non-repetitive peak on-state current	full sine wave; $T_j = 25 \text{ °C prior to}$ surge; see <u>Figure 2</u> and <u>3</u>			
		t = 20 ms	-	140	А
		t = 16.7 ms	-	150	А
l ² t	I ² t for fusing	t = 10 ms	-	98	A ² s
dl _T /dt	rate of rise of on-state current	$I_{TM} = 20 \text{ A}; I_G = 0.2 \text{ A};$ $dI_G/dt = 0.2 \text{ A}/\mu \text{s}$	-	100	A/μs
I _{GM}	peak gate current		-	2	А
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	+150	°C
T _i	junction temperature		-	125	°C

[1] Although not recommended, off-state voltages up to 800 V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15 A/µs.

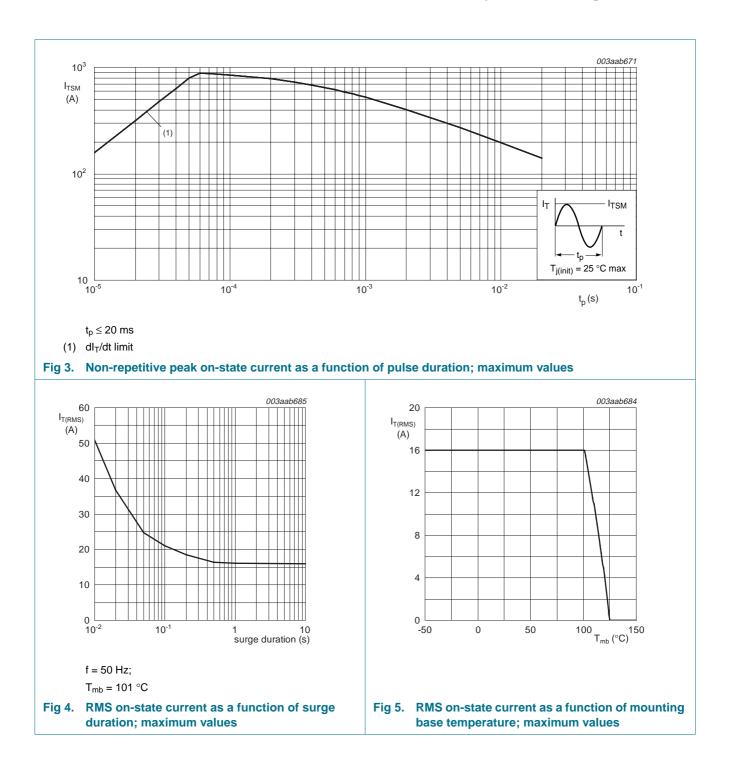
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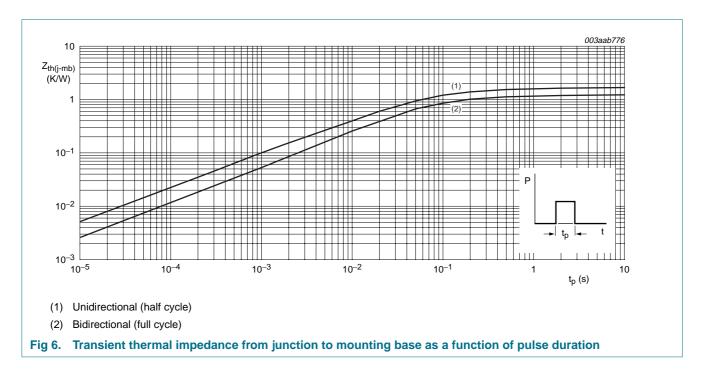
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5. Thermal characteristics

Table 4.	Thermal characteristics						
Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
R _{th(j-mb)}	thermal resistance from junction to	half cycle; see Figure 6	-	-	1.7	K/W	
	mounting base	full cycle; see Figure 6	-	-	1.2	K/W	
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	-	60	-	K/W	



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6. Static characteristics

Table 5. Static characteristics

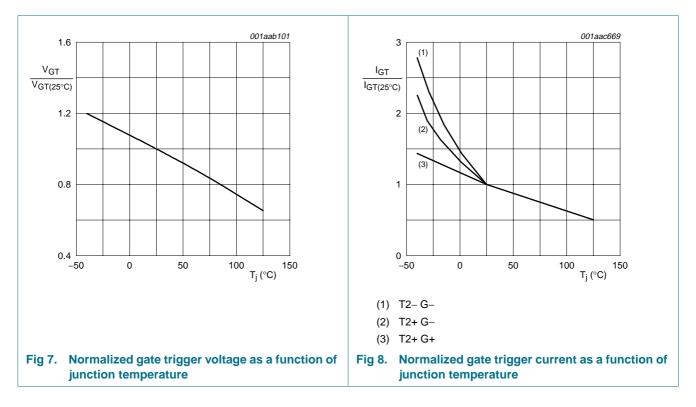
 $T_i = 25 \circ C$ unless otherwise specified.

Symbol	Parameter	Conditions		FA316-6 FA316-8			BTA316-600C BTA316-800C			
			Min	Тур	Max	Min	Тур	Max		
I _{GT}	gate trigger	$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ see } \frac{\text{Figure 8}}{100000000000000000000000000000000000$								
	current	T2+ G+	2	-	50	2	-	35	mA	
		T2+ G–	2	-	50	2	-	35	mA	
		T2- G-	2	-	50	2	-	35	mA	
١L	latching current	$V_D = 12 \text{ V}; \text{ I}_{GT} = 0.1 \text{ A}; \text{ see } \frac{\text{Figure } 10}{100000000000000000000000000000000$								
		T2+ G+	-	-	60	-	-	50	mA	
		T2+ G–	-	-	90	-	-	60	mA	
		T2- G-	-	-	60	-	-	50	mA	
I _H	holding current	$V_D = 12 \text{ V}; \text{ I}_{GT} = 0.1 \text{ A}; \text{ see } \frac{\text{Figure } 11}{100000000000000000000000000000000$	-	-	60	-	-	35	mA	
V _T	on-state voltage	I _T = 18 A; see <u>Figure 9</u>	-	1.3	1.5	-	1.3	1.5	V	
V _{GT}	gate trigger	$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ see } \frac{\text{Figure 7}}{100000000000000000000000000000000000$	-	0.8	1.5	-	0.8	1.5	V	
	voltage	$V_D = 400 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T}_j = 125 \ ^\circ\text{C}$	0.25	0.4	-	0.25	0.4	-	V	
I _D	off-state current	$V_D = V_{DRM(max)}; T_j = 125 \ ^{\circ}C$	-	0.1	0.5	-	0.1	0.5	mA	

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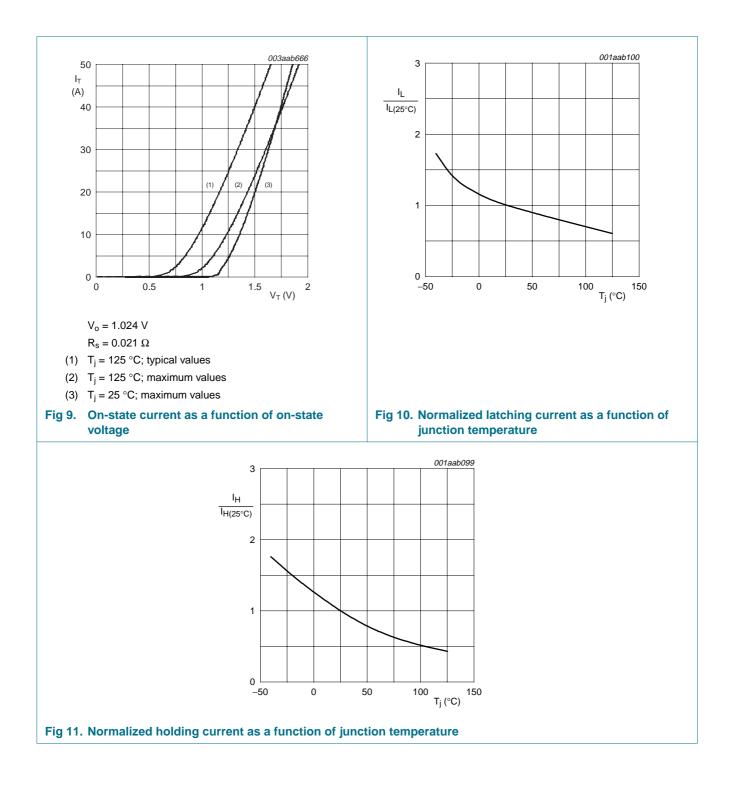
7. Dynamic characteristics

Table 6.	Dynamic cha	racteristics							
Symbol	Parameter	Conditions		A316-6 A316-8		B1 B1	Unit		
			Min	Тур	Max	Min	Тур	Max	
dV _D /dt	rate of rise of off-state voltage	$V_{DM} = 0.67 \times V_{DRM(max)}$; $T_j = 125 \text{ °C}$; exponential waveform; gate open circuit	1000	-	-	500	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	V_{DM} = 400 V; T _j = 125 °C; I _{T(RMS)} = 16 A; without snubber; gate open circuit	20	-	-	15	-	-	A/ms
t _{gt}	gate-controlled turn-on time	$\begin{split} I_{TM} &= 20 \text{ A}; V_D = V_{DRM(max)}; I_G = 0.1 \text{ A}; \\ dI_G/dt &= 5 A/\mu s \end{split}$	-	2	-	-	2	-	μs
	turn-on time	$dI_G/dt = 5 A/\mu S$							



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8. Package outline

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mm	4.7 4.1	1.40 1.25	0.9 0.6	1.45 1.00	0.7 0.4	16.0 15.2	6.6 5.9	10.3 9.7	2.54	15.0 12.8	3.30 2.79	3.0	3.8 3.5	3.0 2.7	2.6 2.2	
ou	4.1 TLINE		0.6	1.00		15.2	5.9	9.7	2.54	12.8	2.79	3.0	3.5 EUR	2.7 OPEAN	2.2	ISSUE DATE
VERSION			IE	C		JEDEC JEITA							PROJECTION		4	
														30		05-03-22

Fig 12. Package outline SOT78 (3-lead TO-220AB)

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Product data sheet

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9. Revision history

Table 7. Revision history	у			
Document ID	Release date	Data sheet status	Change notice	Supersedes
BTA316_SER_B_C_1	20070411	Product data sheet	-	-

BTA316_SER_B_C_1

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10. Legal information

10.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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